

High voltage fast switching NPN power transistor

Datasheet – production data

Features

- High voltage capability
- Fast switching speed

Applications

- Lighting
- Switch mode power supply

Description

This device is a high voltage fast-switching NPN power transistor. It is manufactured using high voltage multi epitaxial planar technology for high switching speeds and medium voltage capability.

It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA. The device is designed for use in lighting applications and low cost switch-mode power supplies.

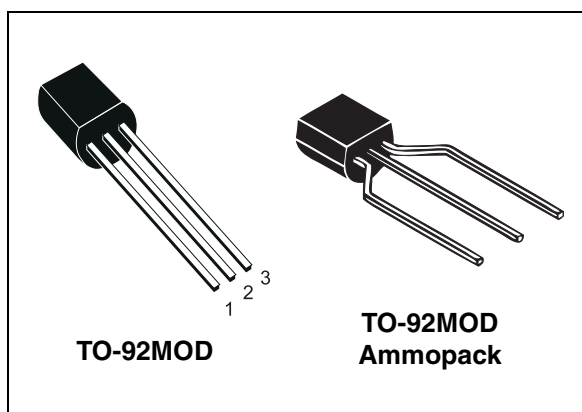


Figure 1. Internal schematic diagram

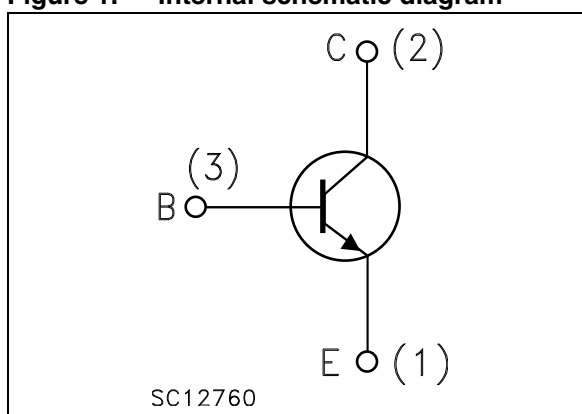


Table 1. Device summary

Order codes	Marking	Package	Packaging
2STL2580	2STL2580	TO-92MOD	Bag
2STL2580-AP	2STL2580	TO-92MOD	Ammopack

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	800	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	9	V
I_C	Collector current	1	A
I_{CM}	Collector peak current ($t_P < 5$ ms)	2	A
I_B	Base current	0.5	A
P_{TOT}	Total dissipation at $T_{amb} = 25$ °C	1.5	W
T_{STG}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJA}	Thermal resistance junction-ambient max	83	°C/W

2 Electrical characteristics

$T_{\text{case}} = 25\text{ °C}$ unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current ($I_{\text{E}} = 0$)	$V_{\text{CB}} = 800\text{ V}$			10	μA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = 8\text{ V}$			100	μA
$V_{(\text{BR})\text{CEO}}^{(1)}$	Collector-emitter breakdown voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 10\text{ mA}$	400			V
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ($I_{\text{C}} = 0$)	$I_{\text{E}} = 100\ \mu\text{A}$	9			V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 250\text{ mA}$ $V_{\text{CE}} = 5\text{ V}$	60	100		
$V_{\text{CE}(\text{sat})}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 0.2\text{ A}$			1	V
$V_{\text{BE}(\text{sat})}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 0.2\text{ A}$			1.1	V
t_{r}	Resistive load Rise time	$V_{\text{CC}}=200\text{ V}$, $I_{\text{C}}=0.3\text{ A}$		140		ns
t_{s}	Storage time	$I_{\text{B}1}=20\text{ mA}$, $I_{\text{B}2}=-50\text{ mA}$		4		μs
t_{f}	Fall time	$T_{\text{p}}=30\ \mu\text{s}$		90		ns

1. Pulse test: pulse duration $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

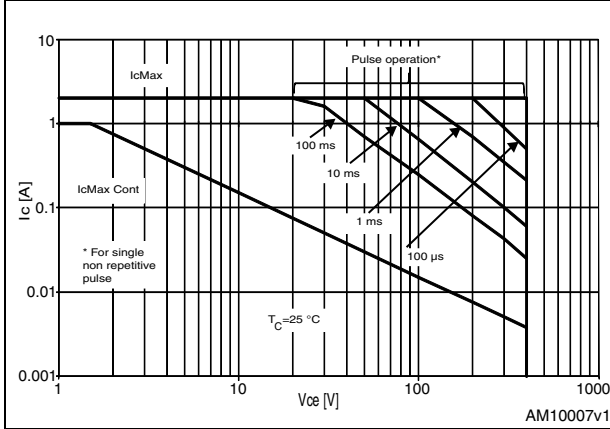


Figure 3. Derating curve

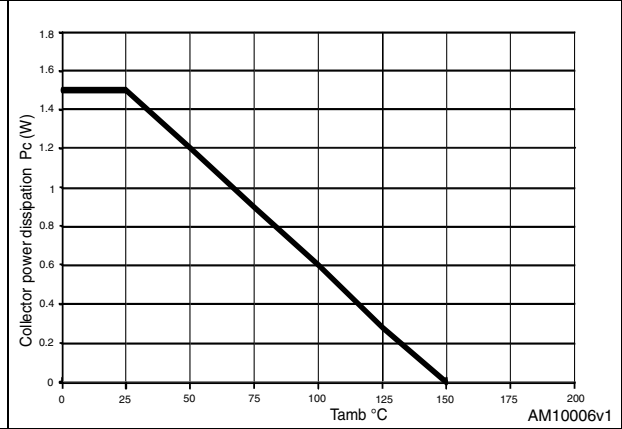


Figure 4. Output curves up to $V_{CE}=2 \text{ V}$

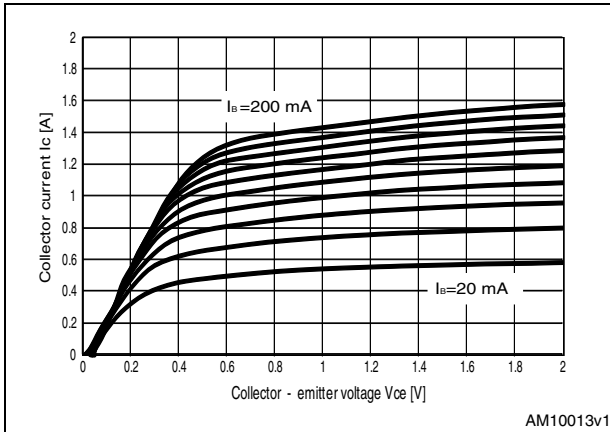


Figure 5. Output curves up to $V_{CE}=10 \text{ V}$

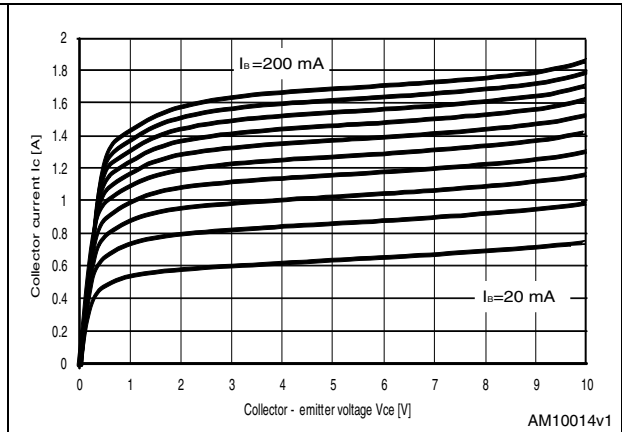


Figure 6. DC current gain ($V_{CE} = 1 \text{ V}$)

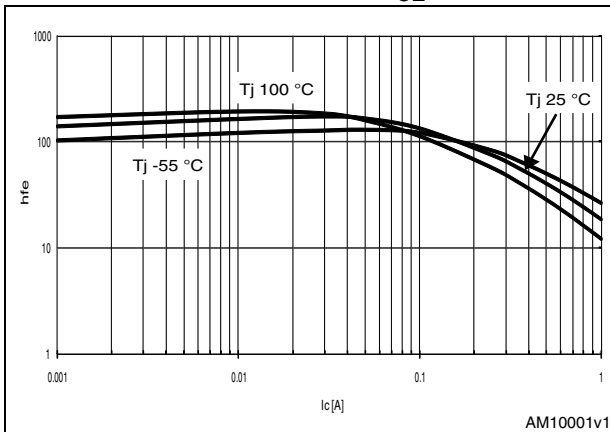


Figure 7. DC current gain ($V_{CE} = 5 \text{ V}$)

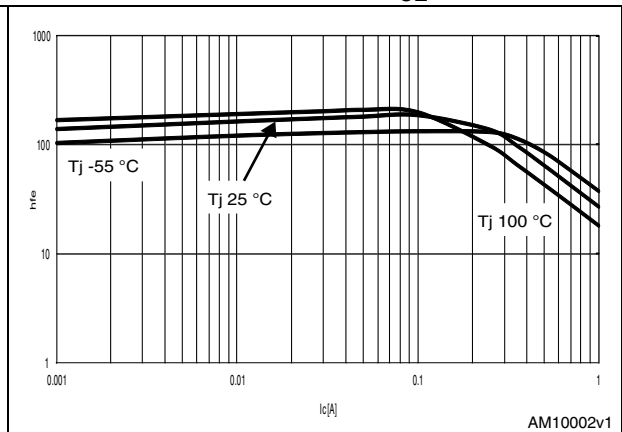


Figure 8. Collector-emitter saturation voltage Figure 9. Base-emitter saturation voltage

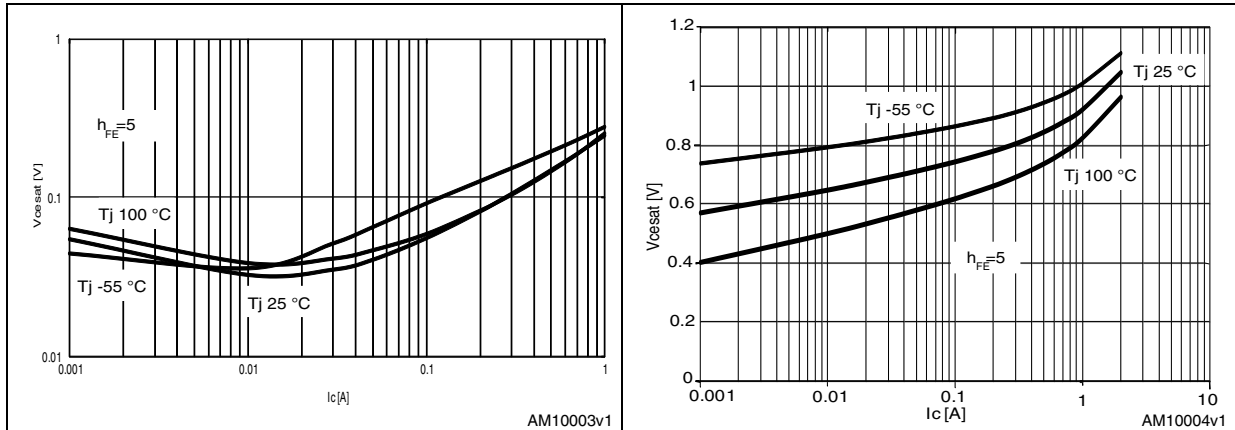


Figure 10. Base-emitter on voltage

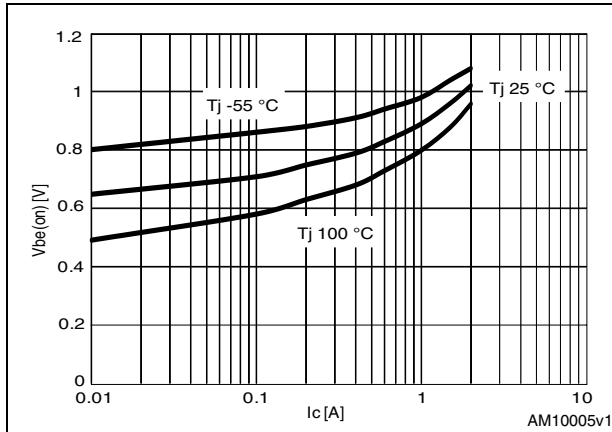


Figure 11. Capacitance variation

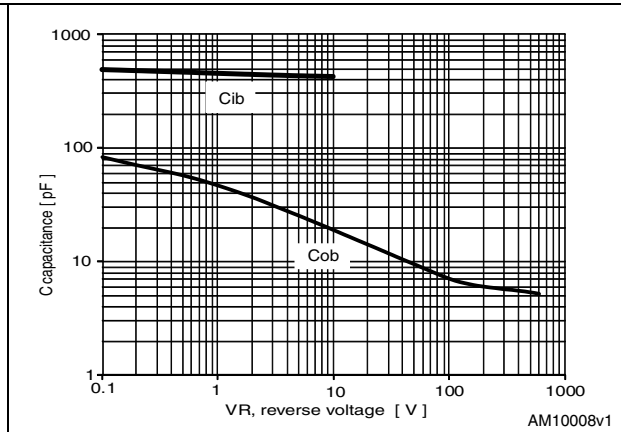


Figure 12. Resistive switching time

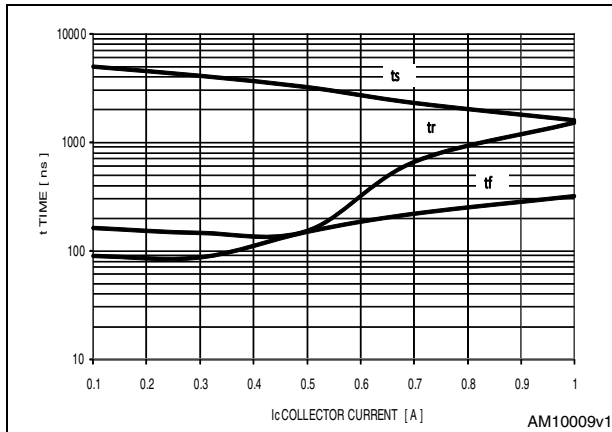


Figure 13. $V_{be(sat)}$ vs. I_c

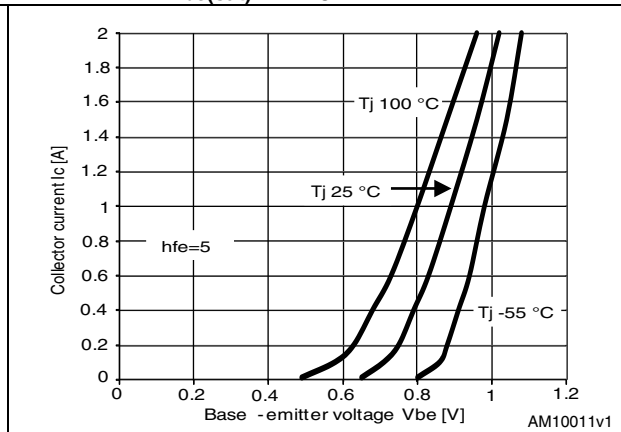
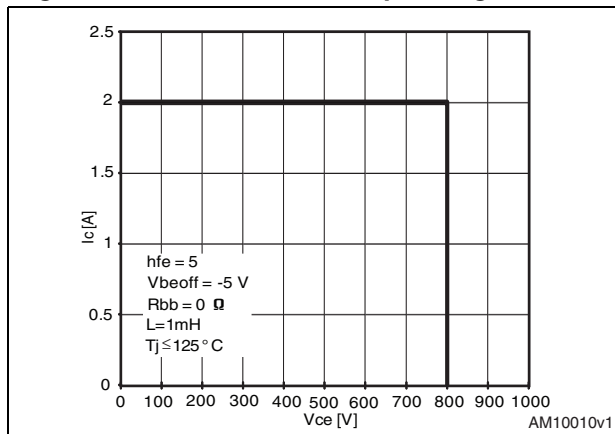


Figure 14. Reverse biased operating area



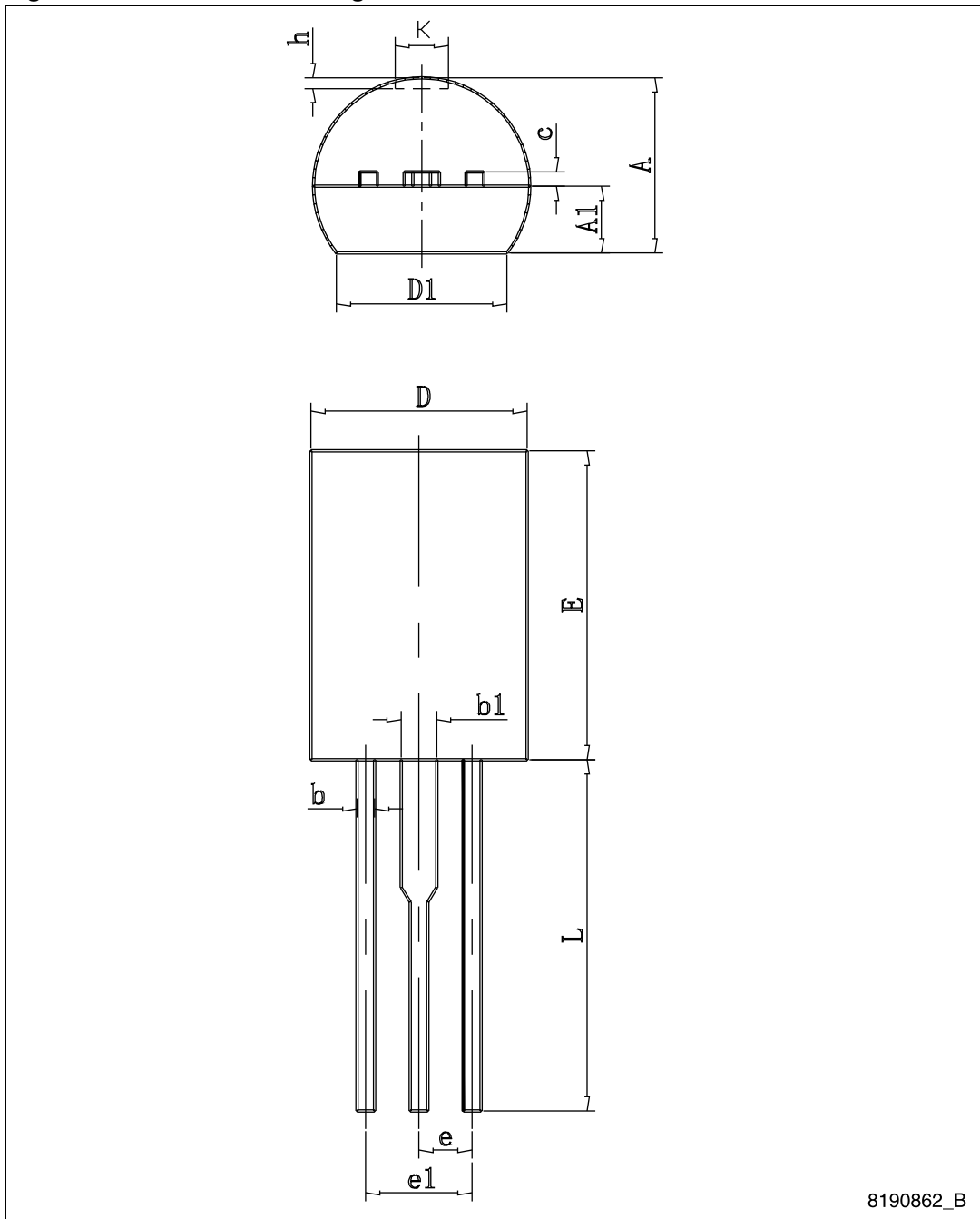
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. TO-92MOD mechanical data

Dim.	mm.		
	Min.	Typ.	Max.
A	4.7		5.1
A1	1.730		2.030
b	0.4		0.6
b1	0.9		1.1
c	0.4		0.5
D	5.8		6.2
D1	4.0		
E	8.4		8.8
e		1.5	
e1	2.9		3.1
L	13.8		14.2
K			1.6
h	0.0		0.380

Figure 15. TO-92MOD drawing mechanical data

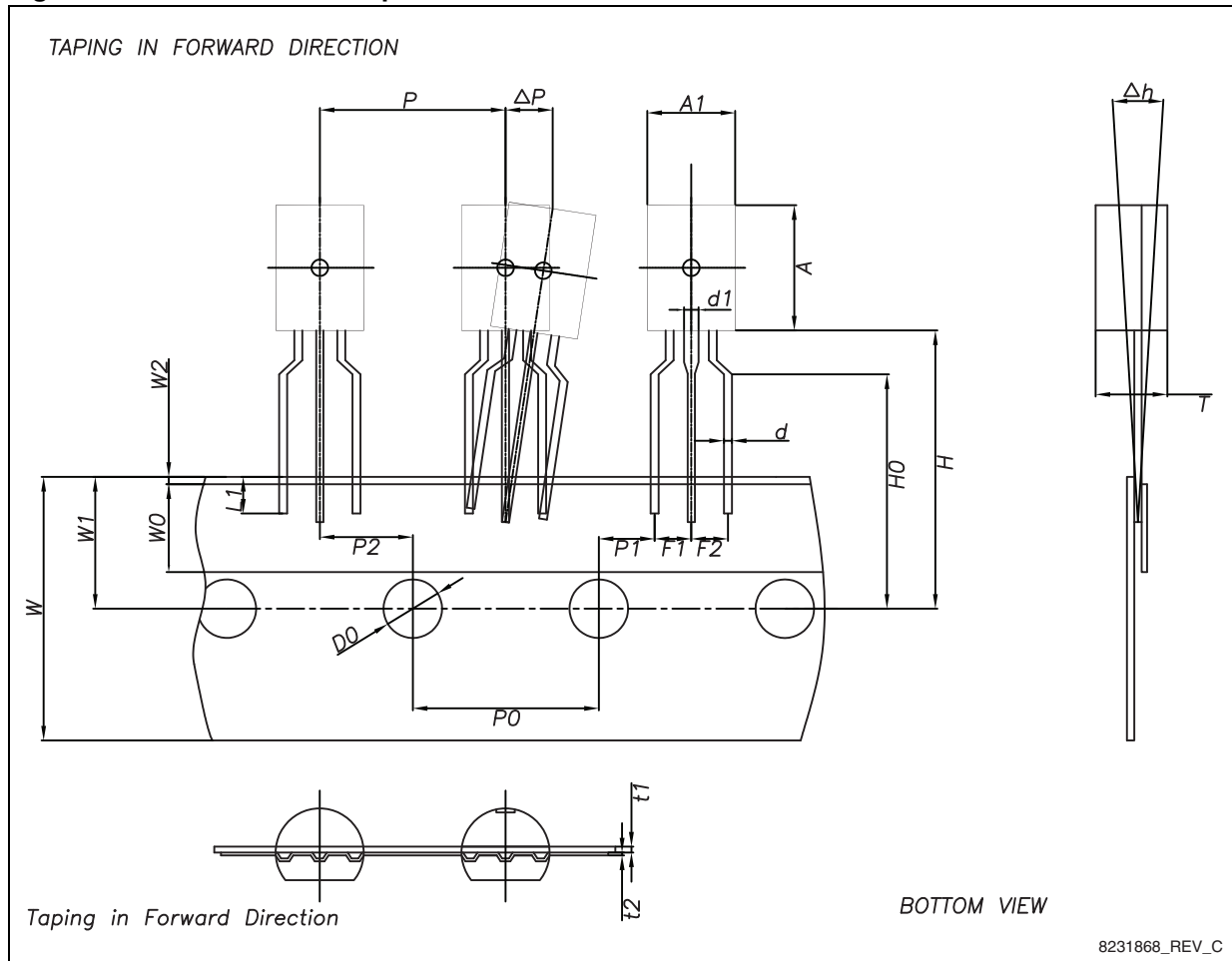


8190862_B

Table 6. TO-92MOD ammopack mechanical data

Dim.	mm.		
	Min.	Typ.	Max.
A1	5.8	6.0	6.2
A	8.4	8.6	8.8
T	4.7	4.9	5.1
d	0.4	0.5	0.6
d1	0.9	1.0	1.1
P	12.4	12.7	13.0
P0	12.5	12.7	12.9
P2	6.05	6.35	6.65
F1, F2	2.2	2.5	2.8
Δh	-1.0	0	1.0
W	17.5	18.0	19.0
W0	5.5	6.0	6.5
W1	8.5	9.0	9.5
W2			1.0
H	18.0	19.0	20.0
H0	15.5	16.0	16.5
L1	2.5		
D0	3.8	4.0	4.2
t1	0.35	0.4	0.45
t2	0.15	0.2	0.25
P1	3.82	3.85	3.88
ΔP	-1.0	0	1.0

Figure 16. TO-92MOD ammopack dimension



4 Revision history

Table 7. Document revision history

Date	Revision	Changes
30-Nov-2010	1	Initial release.
08-Jul-2011	2	Curves inserted
26-Jun-2012	3	Added STL2580-AP order code in TO-92MOD ammopack package

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